

REDUNDANT MODULES 40 AND 80 A DIMENSION SERIES

YR40.241
REDUNDANCY MODULE 24-28V 40A



- 40 and 80 A
- MOSFET transistors
- Minimum power loss
- Compact dimensions

PRODUCT DESCRIPTION

Redundant modules have MOSFET transistors instead of diodes, resulting in lower heat dissipation and voltage drop. Thanks to the MOSFET technology, the modules can be made very compact.

Redundant modules have two separate entrances, each of which can be loaded with half the output current instance. 40 A module can handle up to 20 A per input.

With redundant modules from Pulse, you get a secure system against internal power supply faults which are particularly suitable in processes where downtime is costly.

Redundant module can also be used in systems where you want to ensure the operation of sensitive loads. Input 1 is connected to the main power supply that normally supplies loads directly and eg PLC via redundant module output. Input 2 is connected to a smaller unit that is only connected to the sensitive load via the output, in this case the PLC. In case of failure of the main unit or short circuit at the loads going PLC supplied by the smaller unit and avoids incorrect process output. Redundant module is also suitable when you want to separate the power supply units from the loads to avoid returned voltage, for example, from motors and batteries.

SPECIFICATIONS

Input voltage DC	12-28 V
Input voltage dc min	8,4 V DC
Input voltage dc max	36,4 V DC
Input current per channel max	20 A
Input current at continuous overload or short circuit max	2x32,5 A
Type Power Supply	Redundancy modules
Output voltage	24 V DC
Output Current	40 A
Output Current Max	65 A
Temperature Range Without Derating From	-40 °C
Temperature Range Without Derating To	70 °C

Life span	246000 h @ 2x 20 A, 24 V DC, 40 °C
MTBF (IEC 61709)	2706000 h @ 2x 20 A, 24 V DC, 40 °C
Width	36 mm
Height	124 mm
Depth	127 mm
Weight	0,34 kg
Series	Dimension Y
Approvals	ABS, ATEX, CB, CE, CSA, CSA US, EAC, GL, IECEx, UL
Material Protection	Aluminium
IP Class	IP20
Voltage Drop Over The Semi-Conductor	140 mV

